Preliminary

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCXZ16374FT

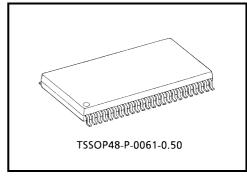
Low-Voltage 16-Bit D-Type Flip-Flop with 5-V Tolerant Inputs and Outputs

The TC74LCXZ16374FT is a high-performance CMOS 16-bit D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 16-bit D-type flip-flop is controlled by a clock input (CK) and a output enable input (\overline{OE}) which are common to each byte. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. When the \overline{OE} input is high, the outputs are in a high impedance state.

When VCC is between 0 and 1.5 V, the LCXZ16374 is in the high-impedance state during power up or power down. This place



Weight: 0.25 g (typ.)

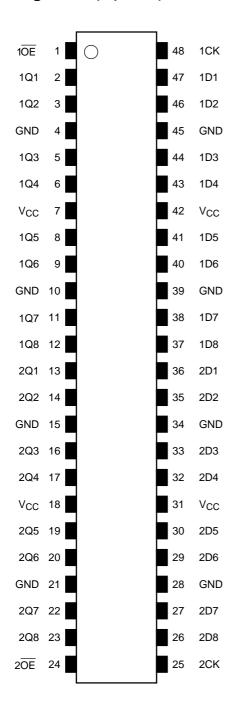
the outputs in high-impedance (Z) state preventing intermittent low impedance loading or glitching in bus oriented applications.

All inputs are equipped with protection circuits against static discharge.

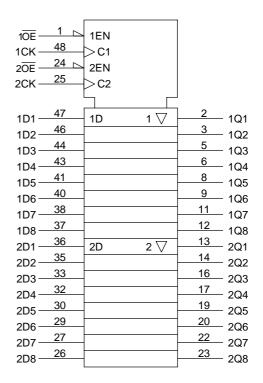
Features

- Low-voltage operation: VCC = 2.7 to 3.6 V
- High-speed operation: $t_{pd} = 6.2 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: TSSOP (thin shrink small outline package)
- · Power-down protection provided on all inputs and outputs
- Supports live insersion/withdrawal: guaranteed power up/down high impedance

Pin Assignment (top view)



IEC Logic Symbol



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Truth Table

	Outputs		
1OE	1CK	1D1-1D8	1Q1-1Q8
Н	Х	Х	Z
L	7	Х	Qn
L		L	L
L		Н	Н

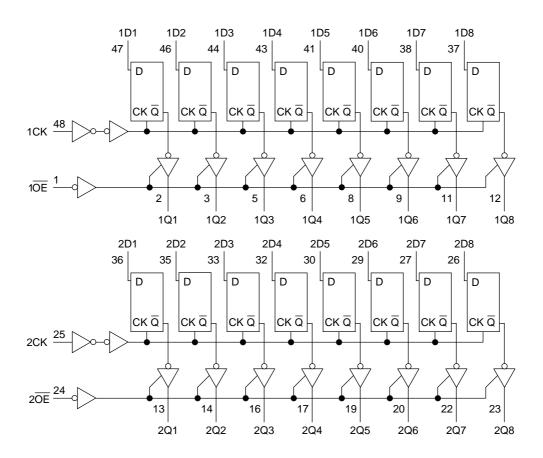
	Inputs			
2 OE	2CK	2D1-2D8	2Q1-2Q8	
Н	Х	Х	Z	
L		Х	Qn	
L	k -1	L	L	
L	★	Н	Н	

X: Don't care

Z: High impedance

Qn: No change

System Diagram





Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
Input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 2)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 3)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Outputs in OFF state or $V_{CC} = 0$ to 1.5 V

Note 2: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Range

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.7 to 3.6	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vour	0 to 5.5 (Note 4)	V	
Output voltage	Vout	0 to V _{CC} (Note 5)		
Output current	lou/lou	±24 (Note 6)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 7)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 4: Output in OFF state or $V_{CC} = 0$ to 1.5 V

Note 5: High or low state

Note 6: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 7: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characterist	Characteristics Symbol Test Condition			Min	Max	Unit		
Characterist	lics	Symbol	rest Condition		V _{CC} (V)	IVIIII	IVIAX	Onit
Input voltage	H-level	V _{IH}		_	2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	8.0	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	-	
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 μA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
				I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	V	V_{OL} $V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.7	_	0.4	
	L-level	VOL		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
3-state output OFF sta	ate current	l _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μА
Power-off leakage cur	rent	l _{OFF}	$V_{IN}/V_{OUT} = 5.5 \text{ V}$		0	_	10.0	μА
Power up/down OFF s	state current	I _{PU/PD}	$V_{OUT} = 0.5 \text{ to } V_{CC}$ $V_{IN} = V_{CC} \text{ or GND}$		0 to 1.5	_	±5.0	μА
			V _{IN} = V _{CC} or GND		2.7 to 3.6	_	225	
Quiescent supply curre	ent	Icc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$	(Note 9)	2.7 to 3.6	_	±225	μΑ
		Δlcc	$V_{IH} = V_{CC} - 0.6 V$ (per	input)	2.7 to 3.6	_	500	

Note 9: Outputs high impedance



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Characteristics Symbol Test Condition			Min	Max	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	IVIIII	IVIAX	Offic
Maximum clock frequency	f _{max}	Figure 1, Figure 2	2.7	_	_	MHz
waxiinum clock frequency	max	riguio i, riguio 2	3.3 ± 0.3	170	_	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	1.5	6.5	ns
(CK-Q)	t _{pHL}	rigule 1, rigule 2	3.3 ± 0.3	1.5	6.2	113
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.7	1.5	6.3	ns
5-state output enable time	t _{pZH}	3.3 ± 0.3	1.5	6.1	113	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	1.5	6.2	ns
3-state output disable time	t _{pHZ}	rigule 1, rigule 3	3.3 ± 0.3	1.5	6.0	115
Minimum pulse width	t _w (H)	Figure 1, Figure 2	2.7	3.0	_	ns
(CK)	t _w (L)	rigule 1, rigule 2	3.3 ± 0.3	3.0	_	115
Minimum setup time	+	Figure 1, Figure 2	2.7	2.5	_	ns
willimum setup time	t _s		3.3 ± 0.3	2.5	_	115
Minimum hold time	+.	Figure 1 Figure 2	2.7	1.5	_	ns
	t _h	Figure 1, Figure 2	3.3 ± 0.3	1.5	_	115
Output to output skew	t _{osLH}	(Note 10)	2.7			ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	115

Note 10: Parameter guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, \, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_f = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	٧
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

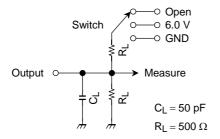
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{\text{IN}} = 10 \text{ MHz}$ (Note	11) 3.3	25	pF

Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ}, t_{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND
t _w , t _s , t _h , f _{max}	Open

Figure 1

AC Waveform

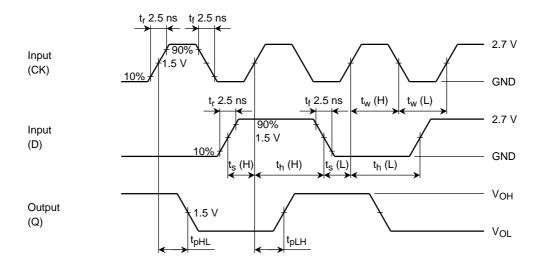


Figure 2 t_{pLH}, t_{pHL}, t_w, t_s, t_h

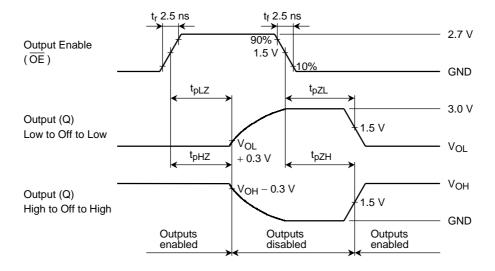
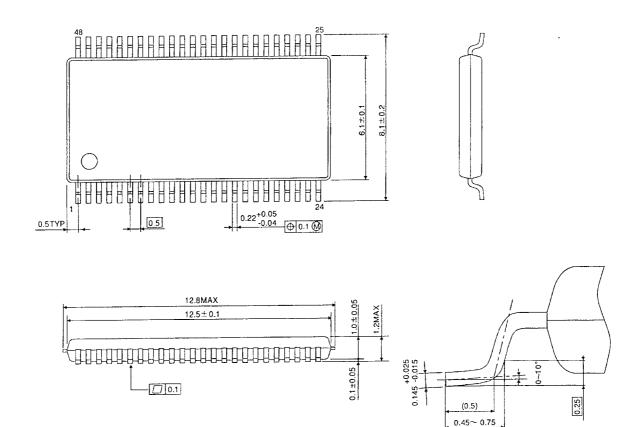


Figure 3 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

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Package Dimensions

TSSOP48-P-0061-0.50 Unit: mm



Weight: 0.25 g (typ.)

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